

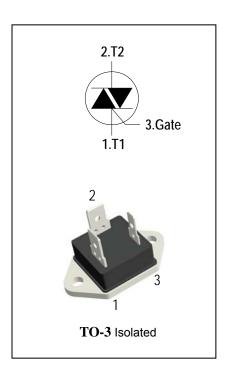
## 3 Quadrants Triacs

### **General Description**

High current density due to mesa technology .the ADS41C triac series is suitable for general purpose AC switching. They can be used as an ON/OFF function in applications such as static relays, heating regulation, High power motor controls e.g. washing machines and vacuum cleaners, Rectifier-fed DC inductive loads e.g.DC motors and solenoids, motor speed controllers.

#### **Features**

- ◆ Repetitive Peak Off-State Voltage: 600Vand800V
- ◆ R.M.S On-State Current (I<sub>T(RMS)</sub>= 40A)
- ◆ High Commutation dv/dt
- ◆ These Devices are Pb-Free and are RoHS Compliant
- ◆ Isolated heatsink mounted , Isolation Voltage ( Viso = 2500V AC )



## **Absolute Maximum Ratings**

Symbol	Items	Conditions		Ratings	Unit
$V_{DRM}$	Depotitive Deals Off State Voltage	T: - 25°C	ADS41C60	600	V
$V_{RRM}$	Repetitive Peak Off-State Voltage	Tj = 25°C	ADS41C80	800	V
$I_{T(RMS)}$	R.M.S On-State Current	T <sub>C</sub> = 80°C		40	Α
I <sub>TSM</sub>	Surge On-State Current	tp=20ms(50Hz)/tp=16.7ms(60Hz)		400/420	Α
l <sup>2</sup> t	I <sup>2</sup> t for fusing	tp=10ms		880	A <sup>2</sup> s
-11/-14	Critical rate of rise of on-state	rate of rise of on-state F = 120 Hz Tj = 125°C		50	A / .
dl/dt	current $I_G = 2 \times I_{GT}$ , tr $\leq 100 \text{ ns}$			50	A/µs
$I_{GM}$	Peak Gate Current	tp = 20 μs Tj = 125°C		8	Α
$P_{G(AV)}$	Average Gate Power Dissipation(Tj=125°C)			1	W
$P_GM$	Peak Gate Power Dissipation(tp=20us,Tj=125°C)			10	W
Tj	Operating Junction Temperature			- 40 ~ 125	°C
T <sub>STG</sub>	Storage Temperature			- 40 ~ 150	°C







## **Electrical Characteristics**( Tj = 25°C unless otherwise specified )

Symbol	Items		Conditions		ADS41C60B/80B	Unit
I <sub>DRM</sub>	Peak Forward Reverse Blocking		V <sub>DRM</sub> = V <sub>RRM</sub> , Tj = 25°C	May	5	uA
I <sub>RRM</sub>	Current		$V_{DRM} = V_{RRM}$ , $Tj = 125$ °C	Max.	5	mA
$V_{TM}$	Peak On-State Voltage		I <sub>TM</sub> = 60A, t <sub>p</sub> = 380 μs	Max.	1.55	V
$V_{GD}$	Q1-Q2-Q3	Non-Trigger Gate Voltage	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $Tj = 125^{\circ}\text{C}$	Min.	0.2	V
V <sub>GT</sub>	Q1-Q2-Q3	Gate Trigger Voltage	10 A D D D D D D D D D D D D D D D D D D	Max.	1.3	V
I <sub>GT</sub>	Q1-Q2-Q3	Gate Trigger Current	$V_D = 12V$ , $R_L = 33\Omega$	Max.	50	mA
I <sub>H</sub>	Q1-Q2-Q3	Holding Current	I <sub>T</sub> = 0.5A	Max.	75	mA
	Q1-Q3	Latelian Const	I <sub>G</sub> = 1.2 I <sub>GT</sub>	Max.	90	mA
I <sub>L</sub>	Q2	Latching Current			110	
dV/dt	Critical Rate of Rise of Off-State  Voltage		$V_D = 2/3V_{DRM}$ gate open Tj = 125°C	Min.	1500	V/µs
(dV/dt)c	Critical Rate of Change of		(dl/dt)c=-20A/ms	Min.	20	V/µs
R <sub>th(j-c)</sub>	Commutating Voltage Tj = 125°C  Junction to case (AC)			Max.	0.9	°C/W
R <sub>th(j-a)</sub>	Junction to ambient			Max.	50	°C/W

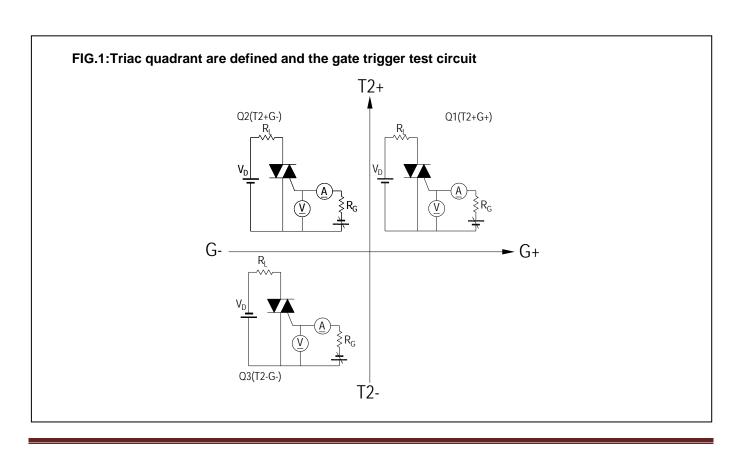




FIG.2: Maximum on-state power dissipation

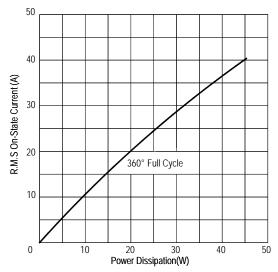


FIG.4: Maximum transient thermal impedance

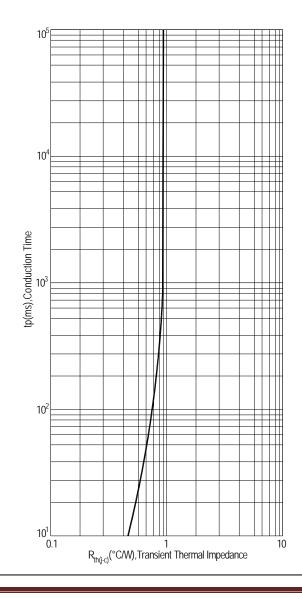


FIG.3: Typical RMS on-state current VS Allowable case Temperature

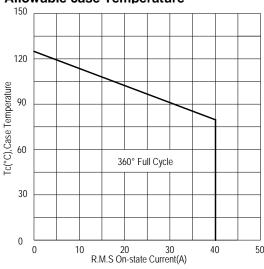


FIG.5: Rated surge on-state current (Non-Repetitive)

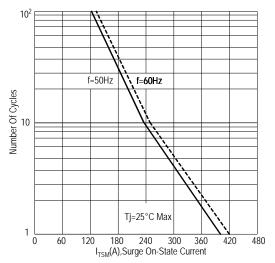


FIG.6: Gate trigger current VS Junction temperature

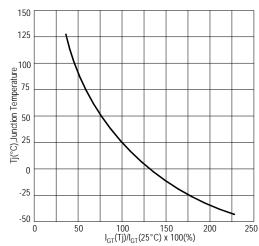




FIG.7:Holding current and Latching current VS Junction temperature

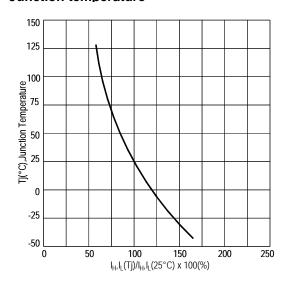


FIG.8: Gate trigger voltage VS Junction temperature

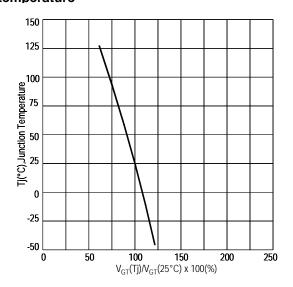
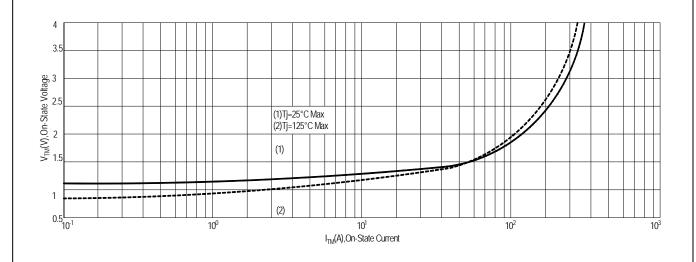


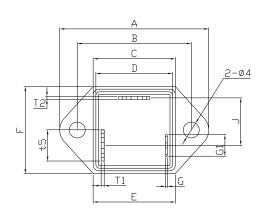
FIG.9: On-state characteristics(Max)

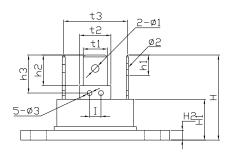


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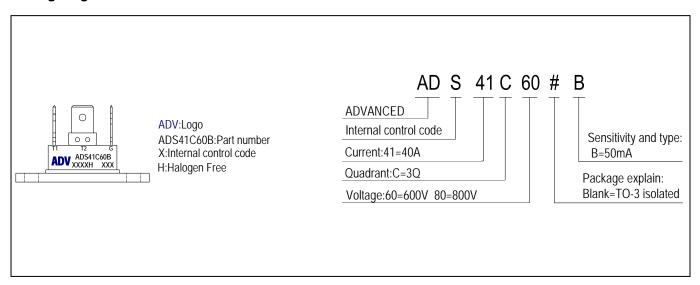
# PACKAGE MECHANICAL DATA TO-3(isolated) Package Dimension





	Dimensions In		Dimensions In		
Symbol	Millimeters		Inches		
	Min	Max	Min	Max	
Α		39.20		1.543	
В	29.80	30.20	1.173	1.189	
С		21.60		0.850	
D		20.20		0.795	
Е		20.10		0.791	
F		23.00		0.906	
G	0.50 typ.		0.020 typ.		
G1	5.70 typ.		0.224 typ.		
T1、T2	0.80 typ.		0.031 typ.		
t1	6.35 typ.		0.250 typ.		
t2、t5	8.25 typ.		0.325 typ.		
J	10.80 typ.		0.425 typ.		
t3	13.90 typ.		0.547 typ.		
H1	10.80 typ.		0.425 typ.		
H2	2.60 typ.		0.102 typ.		
Н		22.50		0.886	
h1	6.20	6.50	0.244	0.256	
h2	7.80	8.10	0.307	0.319	
h3	9.45	10.05	0.372	0.396	
I	2.70	3.30	0.106	0.130	

#### **Making Diagram**



## **Ordering information**

Part number	Package	Marking	Packing	Quantity		
ADS41C60B	TO-3 isolated	ADS41C60B	Tray	80pcs		
ADS41C80B	TO-3 isolated	ADS41C80B	Tray	80pcs		
Note:B = Gate Trigger Current Sensitivity and type						





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